

PATENT
1163-0479P

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant: MURAKAMI, Hideaki Conf.:
Appl. No.: NEW Group:
Filed: November 3, 2003 Examiner:
For: SEMICONDUCTOR STRUCTURE WITH PARTIALLY
ETCHED GATE AND METHOD OF FABRICATING THE
SAME

PRELIMINARY AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

November 3, 2003

Sir:

The following preliminary amendments and remarks are respectfully submitted in connection with the above-identified application.

This amendment includes:

Amendments to the Specification

Remarks